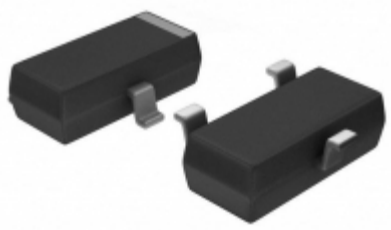









	<b>DDTD113ZC-7-F</b>	
	<b>Hersteller-Teilenummer:</b>	DDTD113ZC-7-F
	<b>Hersteller / Marke:</b>	Diodes Incorporated
	<b>Teil der Beschreibung:</b>	TRANS PREBIAS NPN 200MW SOT23-3
	<b>Datenblätter:</b>	 <a href="#">DDTD113ZC-7-F.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 300000 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

### Spezifikationen

Teilenummer	DDTD113ZC-7-F
Hersteller	Diodes Incorporated
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	300000 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	500mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 2.5mA, 50mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	56 @ 50mA, 5V
Frequenz - Übergang	200MHz
Widerstand - Base (R1) (Ohm)	1k
Widerstand - Emitter-Basis (R2) (Ohm)	10k
Verpackung	Tape & Reel (TR)



















































DDTD113ZC-7-F ist neu im Original, Suche DDTD113ZC-7-F Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DDTD113ZC-7-F Diodes Incorporated mit Garantie und Vertrauen. Anfrage DDTD113ZC-7-F: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>DDTD114GC-7-F</b> Diodes Incorporated TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>DDTD113ZU-7-F</b> Diodes Incorporated TRANS PREBIAS NPN 200MW SOT323</p>	 <p><b>DDTC144WUA-7</b> Diodes Incorporated TRANS PREBIAS NPN 200MW SOT323</p>	 <p><b>DDTD113EU-7-F</b> Diodes Incorporated TRANS PREBIAS NPN 200MW SOT323</p>
 <p><b>DDTD114ECA</b> Original DDTD114ECA Original</p>	 <p><b>DDTC144WUA-7-F</b> Diodes Incorporated TRANS PREBIAS NPN 200MW SOT323</p>	 <p><b>DDTD114EU-7-F</b> Diodes Incorporated TRANS PREBIAS NPN 200MW SOT323</p>	 <p><b>DDTD114EC-7-F</b> Diodes Incorporated TRANS PREBIAS NPN 200MW SOT23-3</p>

### heiße Teile

Mehr

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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